NSN 5961-00-078-6876

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-078-6876 **Inclosure Material:** Metal **Overall Length:** 2.000 inches Overall Diameter: 0.380 inches **End Application:** Airport surveillance radar 9 (asr9) **Mounting Facility Quantity: Mounting Method:** Threaded hole and threaded stud **Overall Width Across Flats:** 0.312 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Function, scd, coaxial crystal detector; reference data, n1n1n1cr2, ti-6310.24, fa 10064, fa 10064, pg 8-7 (aos) pg 8-27, westinghouse; 3a3cr1, ti-6310.27, fa 10078, pg 8-4, westinghouse **Precious Material And Location:** Plated center conductor gold **Precious Material:** Gold **Test Data Document:** 97942-128c529 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator: Terminal Type And Quantity:** 2 connector, coaxial Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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